

# Synthesis of Highly Concentrated ZnO Nanorod Sol by Sol-gel Method and their Applications for Inverted Organic Solar Cells

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**Abstract** – The effects of the zinc oxide (ZnO) preparing process on the performance of inverted organic photovoltaic cells (OPVs) were explored. The morphology and size of ZnO nanoparticles were controlled, leading to more efficient charge collection from device and higher electron mobility compared with nanospheres. Nanosized ZnO particles were synthesized by using zinc acetate dihydrate and potassium hydroxide in methanol. Also, water was added into the reaction medium to control the morphology of ZnO nanocrystals from spherical particles to rods, and  $\text{NH}_4\text{OH}$  was used to prevent the gelation of dispersion. Solution-processed ZnO thin films were deposited onto the ITO/glass substrate by using spin coating process and then ZnO films were used as an electron transport layer in inverted organic photovoltaic cells. The analyses were carried out by using TEM, FE-SEM, AFM, DLS, UV-Vis spectroscopy, current density-voltage characteristics and solar simulator.

Key words: Inverted Organic Photovoltaics, ZnO Thin Films, Morphology Control, Sol-Gel Method

## 1. Introduction

ZnO materials have attracted much interest as an n-type semiconductor due to the wide direct bandgap of 3.37 eV and large exciton binding energy of 60 meV at room temperature [1-3]. The ZnO semiconductor has a good transparency, high electron mobility, excellent chemical and thermal stability in different environments, non-toxicity, good adhesion to substrate, and lower cost [4-8]. Also, ZnO is of interest due to availability of low temperature synthesis and the potential for controlling the morphology through simple processing from solution [9]. The widest varieties of ZnO nanostructures have been reported such as nanospheres, nanorods, nanowires, nanorings, nanoneedles, and so on [10-14]. Many methods for the production of ZnO nanostructures have been reported, such as hydrothermal method, sol-gel method, chemical vapor deposition, thermal decomposition, mechanochemical, and electrochemical deposition [15-18]. Synthesized ZnO nanoparticles have been investigated due to their desirable properties and potential technical applications in different areas such as catalyst, gas sensor, optoelectronic device, and solar cells [19-21]. Especially, OPVs are one of the most promising in solar cell field due to their low cost on flexible plastic substrates, light-weight materials, and easy solution-based fabrication. Conventional OPVs can suffer from the degradation of top electrode (Al, Ca, etc.), because a low work function cathode is susceptible to degradation by moisture

and oxygen in air. Therefore, an inverted device architecture where the nature of charge collection is reversed was used to improve the device lifetime. In the inverted structure, the interface of ITO/PEDOT:PSS can be avoided and the air-sensitive, low work-function Al can be replaced with air-stable, high-work-function metals such as Au and Ag, as shown in Fig. 1(a). Fig. 1(b) shows the energy level diagram of inverted OPVs with well-matched work function. Also, ZnO inter-layer inserted between the active layer and ITO electrode as an electron transport layer to collect the electrons at the electrode has been successfully applied in inverted OPVs [22]. In addition, limitations such as oxidation of the electrode and degradation under oxygen and moisture for conventional OPVs can be overcome [23].

We synthesized ZnO nanostructures using sol-gel method as an electron transport layer in OPVs and investigated the effect of ZnO morphology on OPV performance. To enhance the power conversion efficiency (PCE), the morphology and size of ZnO nanocrystals were controlled from spherical particles to rods. Nanorods could offer the improved electron transport compared with nanosphere. Moreover, addition of  $\text{NH}_4\text{OH}$  results in the stable dispersion of these ZnO particles improving device performance.

## 2. Experimental Section

### 2.1. Materials

Zinc acetate dehydrate (Zn slat, Sigma-Aldrich), potassium hydroxide (KOH, Junsei), and methanol (OCI) were used to prepare the ZnO nanoparticles. Ammonium hydroxide ( $\text{NH}_4\text{OH}$ , Duksan) as stabilizer was used to prevent from gelation after dispersion of ZnO nanorods. For the preparation of ZnO dispersion, 1-butanol (Junsei) was used as an organic medium and 2-(2-methoxyethoxy) acetic

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<sup>‡</sup>This article is dedicated to Prof. Seong-Youl Bae on the occasion of his retirement from Hanyang University.

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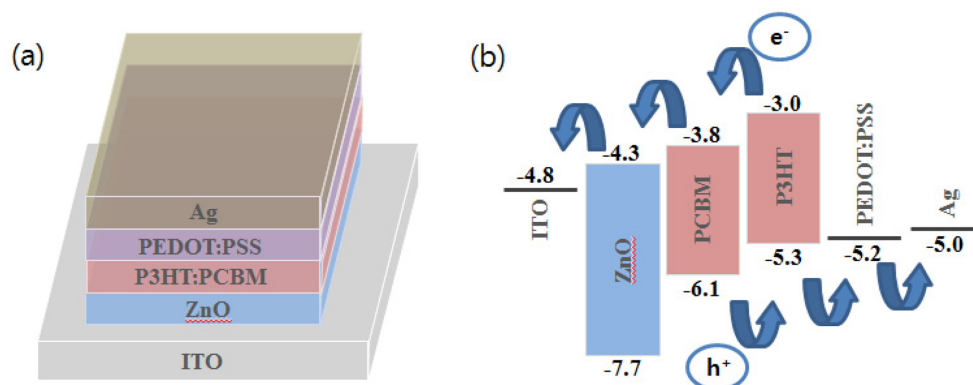


Fig. 1. (a) Device architecture of the inverted OPVs. (b) Schematic energy level diagram of inverted OPVs with a ZnO nanoparticle interlayer. The energies (in eV) are all referenced from the vacuum level.

acid (MEA, Sigma-Aldrich) was used as a dispersant. The slide glasses (Marienfeld-Superior) and the indium tin oxide (ITO)-coated glasses (Geomatec) were used as substrates for the formation of ZnO thin film. Before coating the ZnO thin films, the substrates were cleaned by ultrasonic treatment in acetone (Samchun Company), isopropyl alcohol (IPA, Samchun), and deionized water (Milli-Q Plus system, 18.2 M $\Omega$ ·cm at 25 °C). For the preparation of active layer, 1,2-dichlorobenzene (Sigma-Aldrich), poly(3-hexylthiophene) (P3HT, Merck), and [6,6]-phenyl-C61-butyric acid methyl ester (PCBM, Merck) were used. Poly(3,4-ethylenedioxythiophene):poly(styrene-sulfonate) (PEDOT:PSS, Heraeus P AI 4083) with Triton X-100 (Sigma-Aldrich Chemical Company) was used for the formation of hole transporting layer. All chemical reagents in this research were analytical grades and used without any further purification.

## 2-2. Synthesis of ZnO nanospheres and nanorods

### 2-2-1. ZnO nanosphere synthesis

Spherical ZnO nanoparticles were prepared by using Zn Salt and KOH as starting materials in methanol according to the reported method with some modifications [10]. However, the solvent used for dispersion of ZnO particles was 1-butanol (boiling point: 117.6 °C). In a typical procedure, zinc acetate dehydrate (2.97 g) was dissolved completely in methanol (125 mL) under stirring at 60 °C and then KOH (1.51 g) dissolved completely in methanol (65 mL) at 60 °C was added into zinc acetate dehydrate solution. The molar ratio of Zn salt to KOH was 1 to 2. This mixture was stirred at 60 °C for 3 h and then left to stand at room temperature for 4 h. Precipitate was washed with methanol (100 mL). After the washing step, the methanol was removed by decantation. The washed particles were dispersed in 1-butanol (12 mL) as a solvent for the preparation of ZnO dispersion. The ZnO concentration was in the range 59–83 mg/mL. Then, the MEA (0.04 g) as a ligand was added into the dispersion to improve the dispersion stability of ZnO nanoparticles in 1-butanol. The range of MEA concentration was found to 4–6 wt% with respect to ZnO particles.

### 2-2-2. ZnO nanorod synthesis

Synthetic process for nanospheres was employed up to the point

of the stirring step of the mixture solution at 60 °C before standing for 4 hours. After reaction for 3 h, a small amount of water was added in reaction medium [11]. A different amount of water (1–5 mL) was added to control the size and morphology of ZnO nanorods. This mixture with water was stirred at 60 °C for 3 h and then left to stand at room temperature for 4 h. Washing step of this precipitate and the next process were mentioned in ZnO spheres synthetic process. However, gelation occurred as time passed when more than 4 mL of water was added into ZnO nanorod dispersion. This turbid dispersion became transparent through the addition of NH<sub>4</sub>OH or washing process by centrifugation.

## 2-3. Fabrication of solar cells

Inverted OPV cells composed of ITO/ZnO/P3HT:PCBM/PEDOT:PSS/Ag were fabricated through the following procedure. The ITO substrate was cleaned by sonication with IPA, deionized water, and acetone followed by oxygen plasma treatment. Then, the prepared ZnO dispersions were spin-coated onto the ITO substrates at 3000 rpm for 40 sec and the formed layer was dried at 200 °C for 2 min. The P3HT:PCBM (1:0.7 by weight) blend solution was spin-coated at 900 rpm for 40 sec onto the ZnO layer to form the active layer and baked 90 °C for 10 min. Then, the PEDOT:PSS solution including Triton X-100 (2 wt%) was spin-coated at 4000 rpm for 40 sec onto the active layer, followed by drying at 120 °C for 10 min. Finally, Ag film with 120 nm thickness was deposited by thermal evaporation.

## 2-4. Characterizations

The size and the morphology of ZnO nanoparticles were analyzed by transmission electron microscopy (TEM, JEOL JEM-2100). The ZnO dispersed 1-butanol was placed on the TEM grid and then dried in drying oven. Dynamic light scattering (DLS, Malvern, Zetasizer Nano ZS) was used to investigate the size of ZnO nanoparticles in the dispersion. The light absorbance of dispersions and the transmittance of film were measured with UV-Vis spectrometer (Agilent 8435, Agilent Technologies). Field emission scanning electron microscopy (FE-SEM, FEI Helios NanoLab 650) was used to observe the surface morphology of ZnO films. The surface roughness of ZnO thin

films was observed in  $10\ \mu\text{m} \times 10\ \mu\text{m}$  area using a non-contact mode atomic force microscopy (AFM, Park Systems, XE-100). After the fabrication of inverted OPV cells, the current density-voltage (J-V) curves were measured by using a Keithley 2400 source-measure unit. The photocurrent was obtained under illumination from an Oriel 3A solar simulator (AM 1.5 G). The illumination intensity was calibrated with a Si cell (VLSI standards, Oriel P/N 54450V). The light intensity used in this work was  $100\ \text{mW}/\text{cm}^2$ .

### 3. Results and Discussion

#### 3-1. Effect of ZnO morphological properties attributed to the amount of water

Fig. 2 shows the TEM images of ZnO nanospheres and nanorods

prepared under different conditions. Without the addition of water into reaction medium, nanospheres with 4 nm are shown in Fig. 2(a). To grow into the nanorods, water was added into the reaction medium because a small amount of water was found helpful to increase the ZnO nanocrystal growth rate [24]. The size of ZnO nanoparticles was increased as amount of water increased compared with Fig. 2(a), while there was no morphological change as a result of low water content as in Fig. 2(b) and (c). Depending on the amount of added water, nanospheres with a diameter ranging from 5 to 8 nm can be obtained. As shown in Fig. 2(d), more than 3 ml water was needed to grow the nanorods. With the addition of water into the reaction medium, the length of nanorods was increased from 18 to 25 nm with high uniformity as shown in Fig. 2(d), (e), and (f). The amount of added water into reaction medium was increased from 1 to 5 mL; the particle

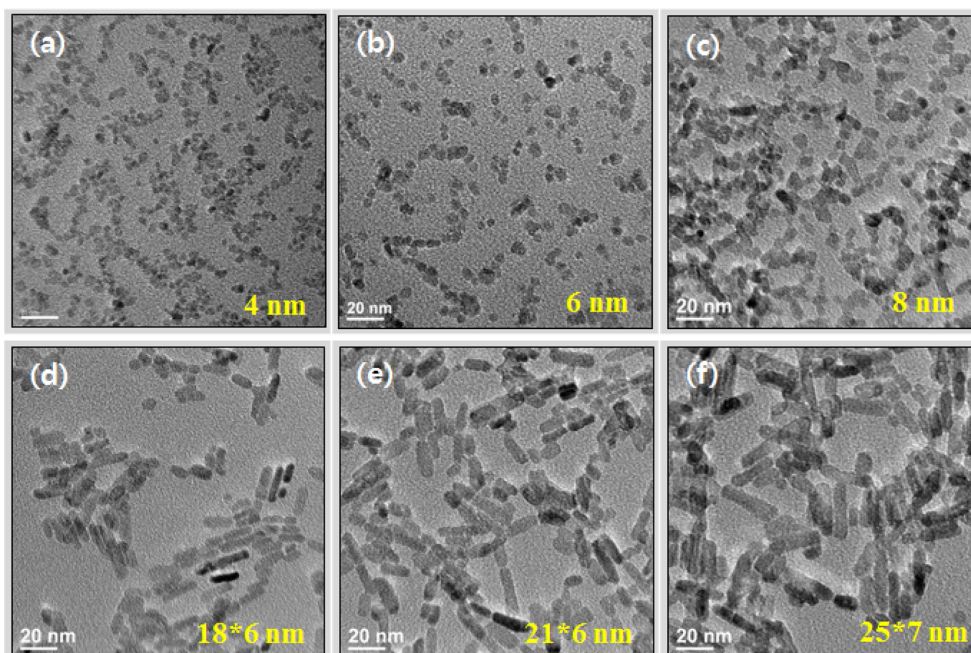


Fig. 2. TEM images of ZnO nanoparticles with different water content: (a) no water, (b) 1 ml, (c) 2 ml, (d) 3 ml, (e) 4 ml, and (f) 5 ml.

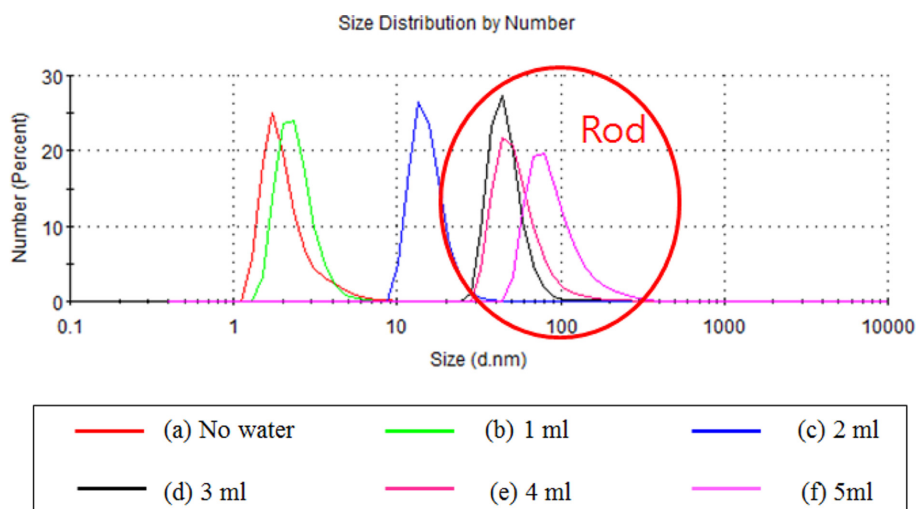


Fig. 3. DLS data of ZnO nanoparticles dispersed in 1-butanol with different water content: (a) no water, (b) 1 ml, (c) 2 ml, (d) 3 ml, (e) 4 ml, and (f) 5 ml.

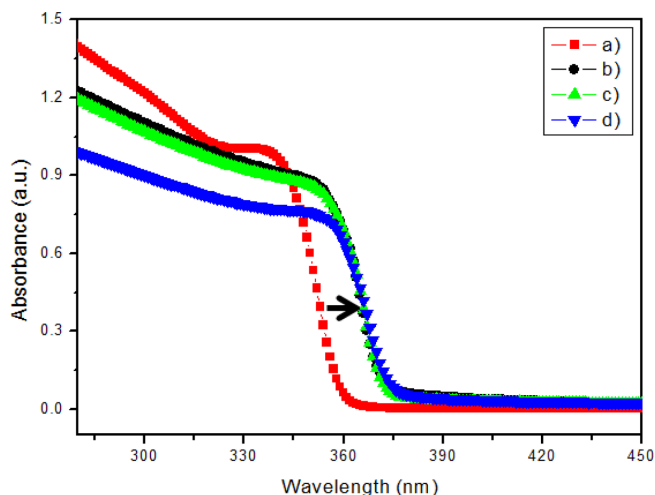


Fig. 4. UV-visible absorption spectra of ZnO dispersion with different water content: (a) no water, (b) 3 ml, (c) 4 ml, and (d) 5 ml.

size was increased with high uniformity. Fig. 3 shows DLS data in a good agreement with TEM images (Fig. 2(a), (b), and (c)) for no water and small amount of water added. However, when water added was more than 3 ml, ZnO dispersions were more opaque according to time passed. This means that there were a few agglomerates. The size distribution of agglomerates in these specimen shows a distribution centered around 50 nm. These results indicate that ZnO existed

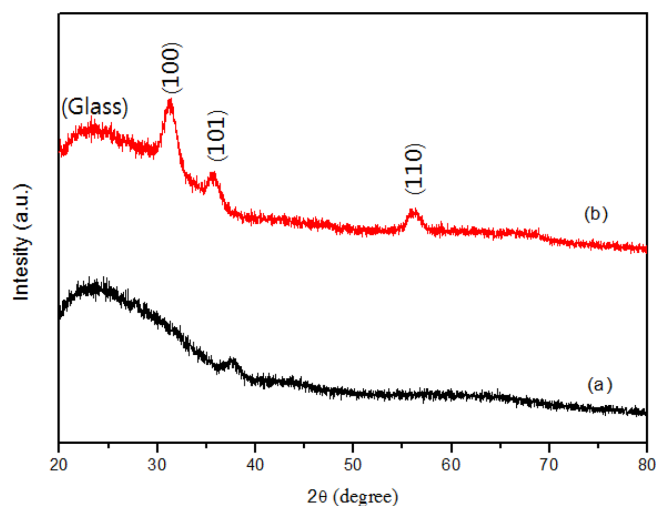


Fig. 5. XRD patterns of ZnO (a) nanospheres (no water) and (b) nanorods (added 5 ml of water) deposited on glass substrate after drying at 200 °C for 2 min.

as an agglomerate structure, consisting of two or three particles, and it is explained by Fig. 3(d), (e), and (f). Also, as shown in Fig. 4, UV-visible absorption spectra could confirm that size of the ZnO particles was increased with water added. It is known that the strong excitonic absorption at ~380 nm has a red shift with the addition of water. This clear red shift in the absorption peak is due to the aggregation of

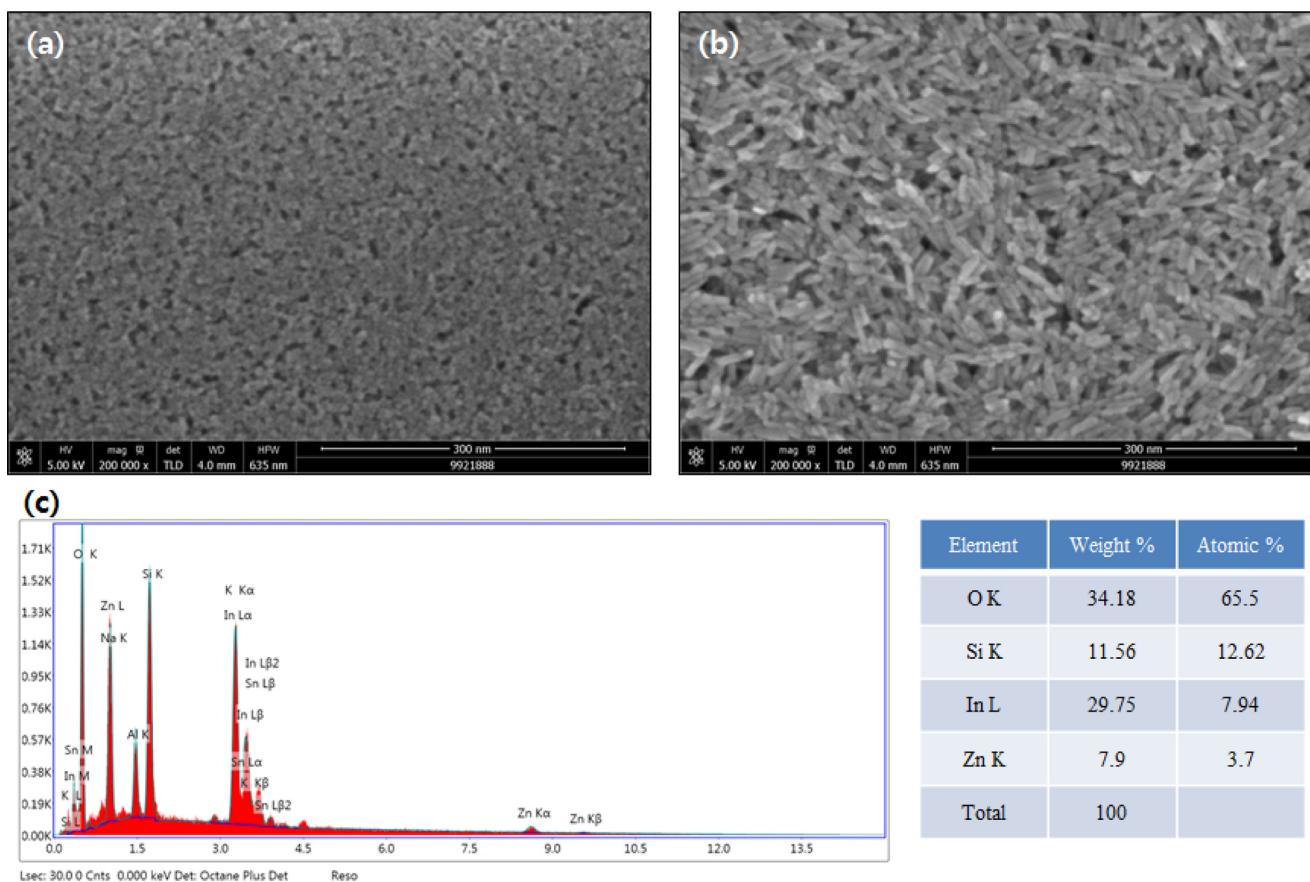


Fig. 6. SEM images of ZnO films deposited on ITO glass substrates using different particles: (a) nanospheres (no water) and (b) nanorods (added 5 ml of water) after drying at 200 °C for 2 min. (c) EDS spectrum of nanorods.



the particles [25]. Fig. 5 shows XRD patterns of the ZnO films. Fig. 5(a) indicates the particle size is so small and film thickness was so thin that it seems like amorphous nature. As shown in Fig. 5(b), the diffraction patterns of the samples exhibit all the characteristic peaks of the hexagonal wurtzite structural ZnO, according to JCPDS card no. 36-1451. No other peaks from impurities were detected, which suggests that only single phase ZnO had formed. Representative SEM images of such as-formed ZnO films deposited using different particles are shown in Fig. 6(a), and (b). The images clearly show that flat surface of film was obtained without defect. Following the ZnO film deposition, a drying process was performed at 200 °C for 2 min under air to densify the structure and remove the organic fraction of the film. The interface of the ZnO nanorods was larger than that of ZnO nanospheres, resulting from morphological properties. That is why efficient electron transport of ZnO nanorod layer could reduce the leakage current. To estimate the composition of the as-grown nanorods, EDS analysis was performed. Fig. 6(c) demonstrates the typical EDS analysis of the as-grown ZnO nanorods. It was confirmed that the grown nanorods are composed of Zn and O elements only. Si and In elements may have resulted from ITO glass sub-

strates.

### 3-2. Influence of colloidal dispersion stability

Spherical dispersion exhibits a high stability, and their size and shape maintain at approximately >90% of their original values even after storage for 90 days. However, nanorod dispersions form gel after 1 day, depending on the amount of water. The sol-gel synthesis of metal oxides can be performed via the hydrolysis and condensation of metal cations. When hydrolysis rates are faster than condensation rate, gelation occurs [26]. We suppose that addition of water for nanorods increases the hydrolysis rate. Inset of Fig. 7(a) shows optical photograph of 1-butanol solution of the ZnO nanorods, which is opaque dispersion formed gelation. After the addition of  $\text{NH}_4\text{OH}$  to solve this problem, nanorod dispersions did not form gel, as shown in inset of Fig. 7(b). Also, the  $\text{NH}_4\text{OH}$  shifted the pH of the solution towards alkaline deposition, which resulted in accelerated rate of

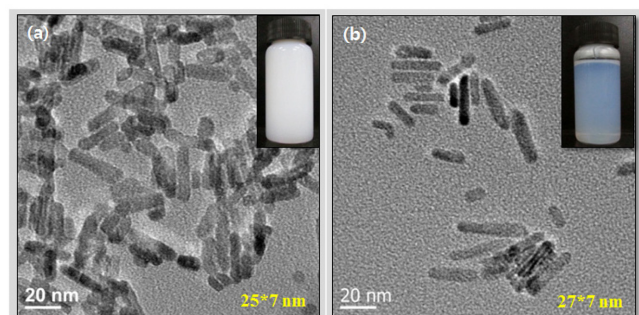


Fig. 7. TEM images of ZnO nanorod synthesized using 5 ml of water (b) with  $\text{NH}_4\text{OH}$ . The inset presents photographs of ZnO dispersion.

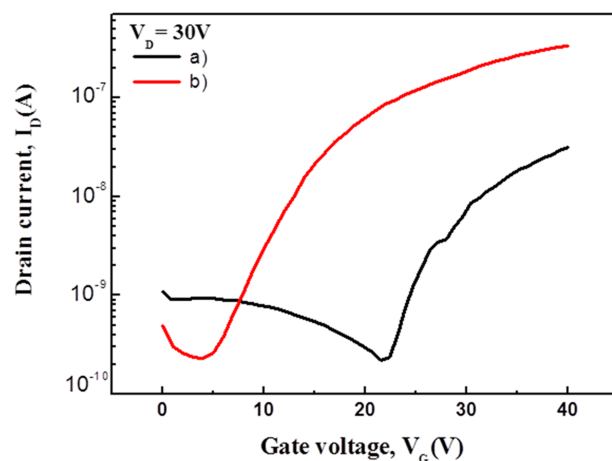


Fig. 9. Transfer characteristics ( $I_D$ - $V_G$ ) of TFTs fabricated with (a) ZnO nanospheres (no water) and (b) nanorods (added 5 ml of water with  $\text{NH}_4\text{OH}$ ).

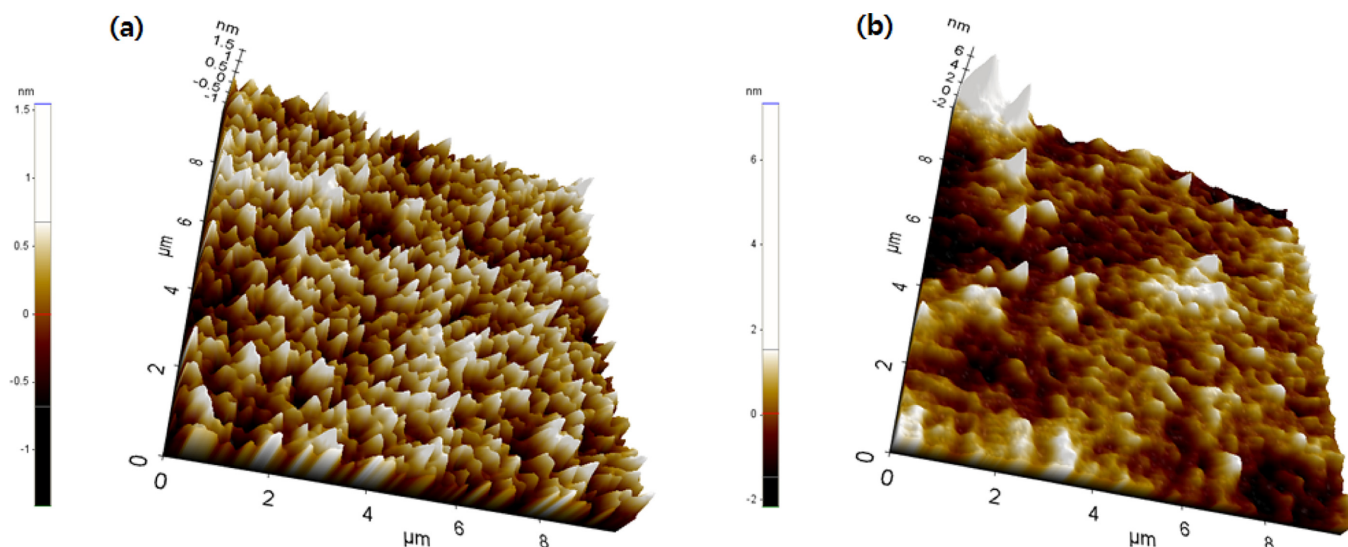


Fig. 8. 3D AFM images of ZnO (a) nanospheres (no water) and (b) nanorods (added 5 ml of water with  $\text{NH}_4\text{OH}$ ) deposited on ITO/glass substrates. The rms roughnesses over the  $10\text{ }\mu\text{m}\times 10\text{ }\mu\text{m}$  areas are 0.38 and 0.77 nm, respectively.

condensation than hydrolysis. This favors agglomeration of larger particles, as shown in Fig. 7(b) [27]. Fig. 8 shows the surface roughness variation as morphology of ZnO nanoparticles. The ZnO nanosphere film was considerably smoother with a root-mean-square (rms) surface roughness ( $R_{\text{rms}}$ ) of 0.38 nm. The ZnO nanorod film was relatively high  $R_{\text{rms}}$  of 0.77 nm due to large particle size. The difference in the film morphologies can be correlated with the particle shape. This film having rough structure, leading to lower leakage current due to the improvement in hole blocking capability and electron collection efficiency, enhanced the device performance [28]. Fig. 9 shows current-voltage characteristics of TFT fabricated by using ZnO with two different particles as the semiconducting layer. The  $I_D$ - $V_G$  curves reveal that the on/off current ratio of TFT with ZnO nanorods is larger than that of TFT with ZnO nanospheres, and the ratio is higher than  $10^3$ . The extracted field effect mobility of TFT with ZnO nanorods is calculated to be  $1.0 \times 10^{-3} \text{ cm}^2/\text{Vs}$ , which is higher than that of TFT with nanospheres ( $2.9 \times 10^{-4} \text{ cm}^2/\text{Vs}$ ). This electron mobility difference in ZnO films is caused by the increased interfacial area as morphology of ZnO nanoparticles was controlled. Definitely, mobility of this ZnO film used as inter layer between the active layer and ITO electrode in inverted OPVs for electron extraction and transportation will affect the photovoltaic performance of resulting inverted OPVs.

Fig. 10 shows the current-voltage characteristics under  $100 \text{ mW} \cdot \text{cm}^{-2}$  of the inverted organic photovoltaic cells processed from ZnO nanoparticles of various parameters. The corresponding photovoltaic parameters are summarized in Table 1. Clearly, the device performance is

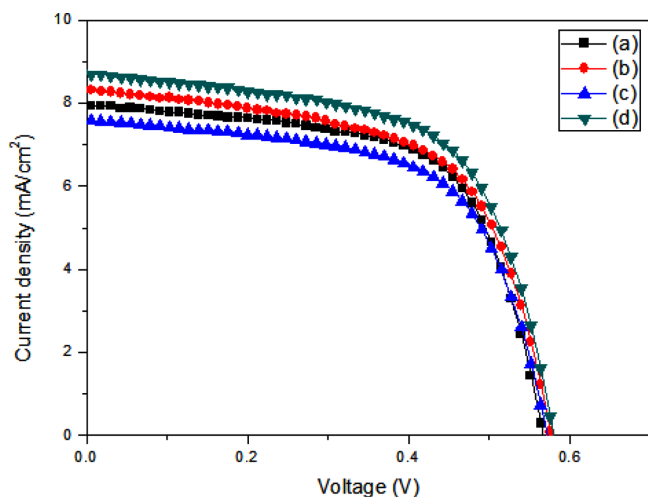


Fig. 10. J-V characteristics of the devices with ZnO nanoparticles from different water content (a) No water, (b) 3 ml, (c) 5 ml, and (d) 5 ml with addition of  $\text{NH}_4\text{OH}$ .

enhanced significantly by highly stable ZnO nanorods film. The inverted device fabricated from ZnO nanosphere film without addition of water exhibits open circuit voltage ( $V_{oc}$ ) of 0.57 V, short circuit current density ( $J_{sc}$ ) of  $7.94 \text{ mA}/\text{cm}^2$ , fill factor (FF) of 63.44, and PCE of 2.85%. When using ZnO nanorods film with addition of water (3 mL), PCE of the inverted device was improved to 2.91% with  $V_{oc}$  of 0.58 V,  $J_{sc}$  of  $8.32 \text{ mA}/\text{cm}^2$ , and FF of 60.8. Also, ZnO dispersion having high uniformity and crystallinity made by increasing addition of water amount to 5 mL and prevented from gelation by using  $\text{NH}_4\text{OH}$  led to both a larger  $J_{sc}$  and FF of the inverted device due to their higher electron mobilities and optical transparency [29]. It can be seen that the device performance largely depends on  $J_{sc}$ . The  $J_{sc}$  of the device is affected by the morphology of particles and stability of dispersion. As shown in Table 1, maximum  $J_{sc}$  is obtained with nanorods and addition of  $\text{NH}_4\text{OH}$ . This result indicates that ZnO nanorod increased the interfacial area of the device, leading to more efficient charge collection from device and higher electron mobility compared to nanospheres [30,31].

#### 4. Conclusions

Morphology and size of ZnO nanocrystals were controlled from spherical particles to rods with the addition of water in modified sol-gel method and dispersed in 1-butanol for inverted OPVs as an electron transport layer.  $\text{NH}_4\text{OH}$  was added before washing step to prevent gelation of ZnO dispersion. The morphology of ZnO nanoparticles plays an important role in electron transport between the active layer and ITO electrode. Stable ZnO nanorod dispersion by the added  $\text{NH}_4\text{OH}$  showed much better electrical characteristics than ZnO nanosphere dispersion. PCE of device with nanorod film was increased due to the electron mobility of more than three times from  $2.9 \times 10^{-4}$  to  $1.0 \times 10^{-3} \text{ cm}^2/\text{Vs}$  by controlling morphology and size of ZnO particles from spheres. These results indicate that the device performance was strongly dependent on the morphology of ZnO particles and dispersion stability. The optimized inverted OPVs with nanorods demonstrated an enhanced PCE of 16% from 2.68% to 3.12% compared with inverted OPV cell without  $\text{NH}_4\text{OH}$ .

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Table 1. Summary of device performance

Device	Shape of ZnO	Amount of water	Addition of $\text{NH}_4\text{OH}$	$V_{oc}$ (V)	$J_{sc}$ ( $\text{mA}/\text{cm}^2$ )	FF	PCE (%)
(a)	Spheres	No water	N/A	0.57	7.94	63.44	2.85
(b)	Rods	3ml	N/A	0.58	8.32	60.80	2.91
(c)	Rods	5ml	N/A	0.57	7.56	62.11	2.68
(d)	Rods	5ml	0.5 ml	0.58	8.69	61.91	3.12

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